# **RENESAS** 2SA778(K), 2SA778A(K)

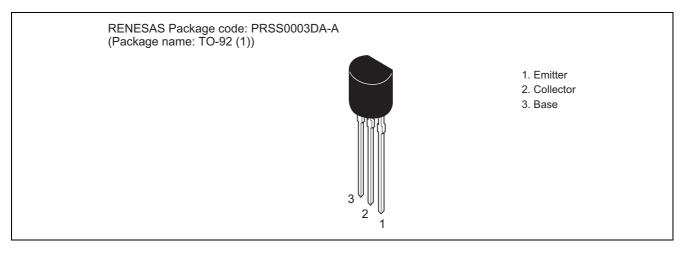
Silicon PNP Epitaxial

REJ03G0628-0300 Rev.3.00 Jul 30, 2007

# Application

High voltage medium speed switching

# Outline



# **Absolute Maximum Ratings**

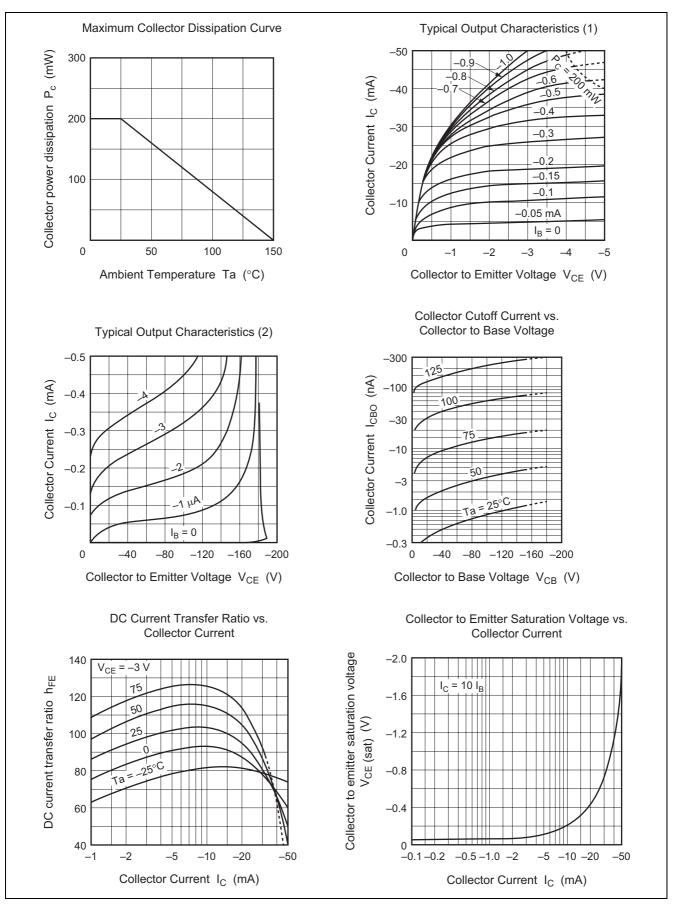
				$(Ta = 25^{\circ}C)$
Item	Symbol	2SA778(K)	2SA778A(K)	Unit
Collector to base voltage	V <sub>CBO</sub>	-150	-180	V
Collector to emitter voltage	V <sub>CEO</sub>	-150	-180	V
Emitter to base voltage	V <sub>EBO</sub>	-5	-5	V
Collector current	Ι <sub>C</sub>	-50	-50	mA
Collector power dissipation	Pc	200	200	mW
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	°C

# **Electrical Characteristics**

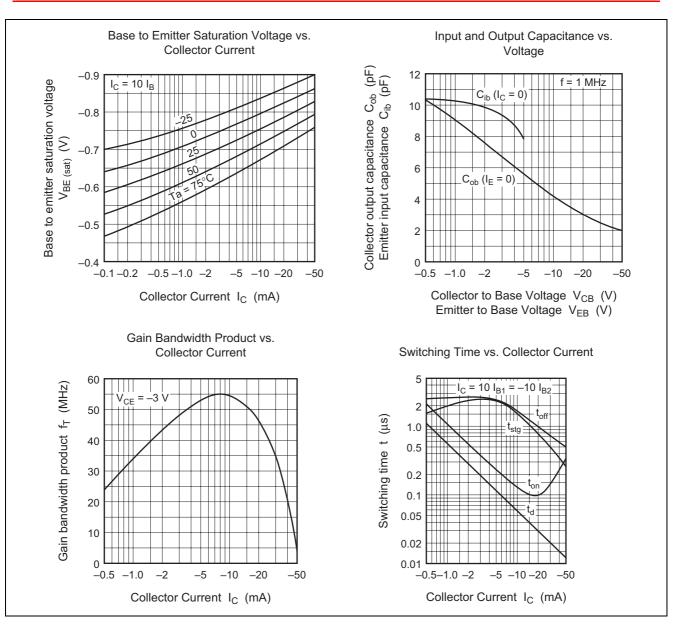
 $(Ta = 25^{\circ}C)$ 

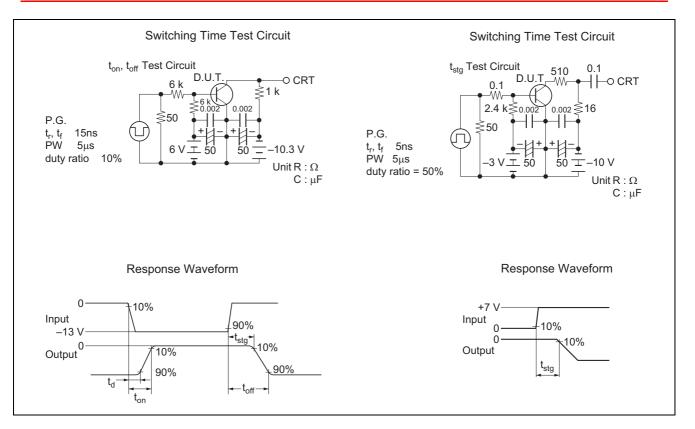
		2SA778(K)		2SA778A(K)					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V <sub>(BR)CBO</sub>	-150	—	—	-180	—	—	V	$I_{C} = -50 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	V <sub>(BR)CER</sub>	-150		_	-180	_	_	V	I <sub>C</sub> = -50 μA, R <sub>BE</sub> = 30 kΩ
Collector cutoff current	I <sub>CBO</sub>			-1.0				μA	$V_{CB} = -100 \text{ V}, I_E = 0$
		_	_			_	-1.0	μΑ	$V_{CB} = -150 \text{ V}, I_E = 0$
Emitter cutoff current	I <sub>EBO</sub>		—	-1.0	_		-1.0	μA	$V_{EB} = -5 V, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	30	100	—	40	100	200		$V_{CE} = -3 V$ , $I_E = -15 mA$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	-0.3	-1.0	—	-0.3	-1.0	V	$I_{\rm C} = -15 \text{ mA},$ $I_{\rm B} = -1 \text{ mA}$
Base to emitter saturation voltage	$V_{\text{BE(sat)}}$		-0.77	-1.0	—	-0.77	-1.0	V	$I_{\rm C} = -15 \text{ mA},$ $I_{\rm B} = -1 \text{ mA}$
Collector output capacitance	Cob		_	10	—	—	10	pF	$V_{CB} = -10 \text{ V}, I_E = 0,$ f = 1 MHz
Gain bandwidth product	f⊤		50	—	—	50	—	MHz	$V_{CE} = -3 V,$ $I_{C} = -15 mA$
Turn on time	t <sub>on</sub>		135			135		ns	$V_{CC} = -10.3 V$
Turn off time	t <sub>off</sub>	—	1.7	—	—	1.7	—	μs	$I_{C} = 10 I_{B1} = -10$ $I_{B2} = -10 \text{ mA}$
Storage time	t <sub>stg</sub>		_	1.0	_	_	1.0	μs	$V_{CC} = -10 V,$ $I_{C} = -17 mA$ $I_{B1} = -1mA,$ $I_{B2} = -12 mA$

# **Main Characteristics**

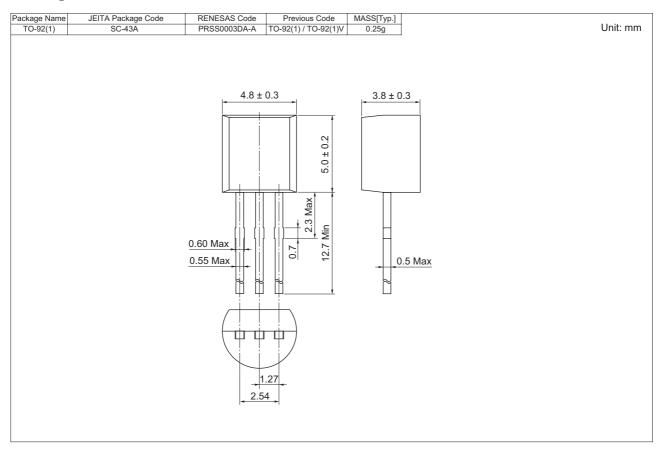


RENESAS





# **Package Dimensions**



# **Ordering Information**

Part No.	Quantity	Shipping Container
2SA778KTZ	2500	Hold Box, Radial Taping
2SA778AKTZ		

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

# RenesasTechnology Corp. sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

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### Renesas Technology America, Inc.

450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K. Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd. Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd. 7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

Renesas Technology Taiwan Co., Ltd. 10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

## Renesas Technology Singapore Pte. Ltd.

1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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